Z0103MN

Logic level four-quadrant triac

Rev. 03 — 5 August 2009

Product data sheet

1. Product profile

1.1 General description

Passivated sensitive gate 4-Q triac in a SOT223 surface-mountable plastic package

1.2 Features and benefits

- Direct interfacing to logic level ICs
- Direct interfacing to low power gate drive circuits
- High blocking voltage of 600V
- Sensitive gate in four quadrants
- Surface-mountable package

1.3 Applications

- General purpose low power motor control
- Home appliances

- Industrial process control
- Low power AC Fan controllers

1.4 Quick reference data

Table 1. Quick reference

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	-	600	V
I _{T(RMS)}	RMS on-state current	half sine wave; T _{sp} ≤ 89 °C; see <u>Figure 1</u> and <u>4</u>	-	-	1	A
Static ch	aracteristics					
I _{GT}	gate trigger current	$V_D = 12 \text{ V; } T_j = 25 \text{ °C;}$ T2+ G-; see <u>Figure 6</u>	-	-	3	mA
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C};$ T2- G-	-	-	3	mA
		V _D = 12 V; T _j = 25 °C; T2+ G+	-	-	3	mA
		V _D = 12 V; T _j = 25 °C; T2- G+	-	-	5	mA



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2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1		N.I.
2	T2	main terminal 2	4	T2T1
3	G	gate		`G sym051
4	T2	main terminal 2		
			SOT223 (SC-73)	

3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
Z0103MN	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223		

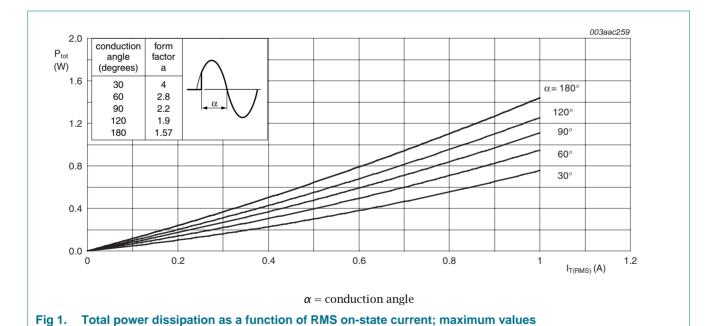
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4. Limiting values

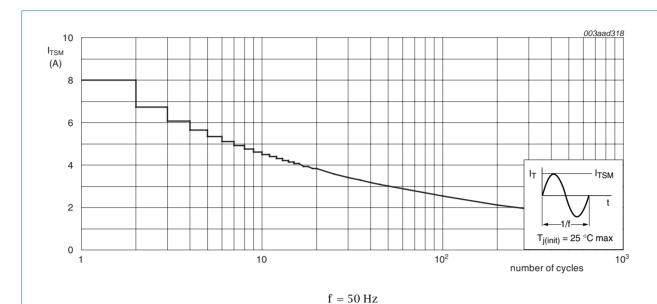
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	600	V
$I_{T(RMS)}$	RMS on-state current	half sine wave; $T_{sp} \le 89 ^{\circ}\text{C}$; see Figure 1 and 4	-	1	Α
dI _T /dt	rate of rise of on-state	$I_T = 1 \text{ A}$; $I_G = 20 \text{ mA}$; $dI_G/dt = 100 \text{ mA/}\mu\text{s}$; T2+ G-	-	50	A/µs
	current	$I_T = 1 \text{ A}$; $I_G = 20 \text{ mA}$; $dI_G/dt = 100 \text{ mA/}\mu\text{s}$; $T2+ G+$	-	50	A/µs
		$I_T = 1 \text{ A}$; $I_G = 20 \text{ mA}$; $dI_G/dt = 100 \text{ mA/}\mu\text{s}$; T2- G+	-	20	A/µs
		$I_T = 1 \text{ A}$; $I_G = 20 \text{ mA}$; $dI_G/dt = 100 \text{ mA/}\mu\text{s}$; T2- G-	-	50	A/µs
I_{GM}	peak gate current		-	1	Α
P_{GM}	peak gate power		-	2	W
T _{stg}	storage temperature		-40	150	°C
T _j	junction temperature		-	125	°C
I _{TSM}	non-repetitive peak	full sine wave; $t_p = 16.7 \text{ ms}$; $T_{j(init)} = 25 \text{ °C}$	-	8.5	Α
	on-state current full sine wave; $t_p = 20$ ms; $T_{j(init)} = 25$ °C; see Figure 2 and 3	-	8	Α	
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	0.32	A^2s
$P_{G(AV)}$	average gate power		-	0.1	W



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Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum

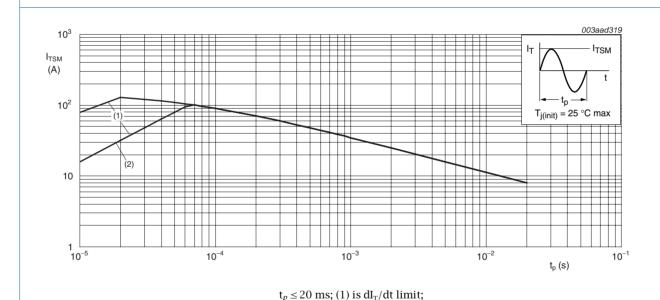
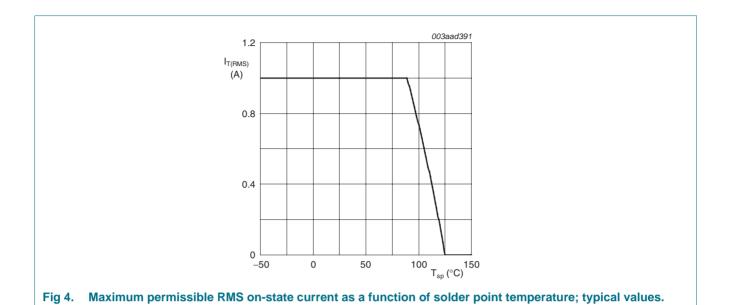


Fig 3. Non-repetitive peak on-state current as a function of pulse width; maximum values

values

(2) is T2 - G + quadrant limit

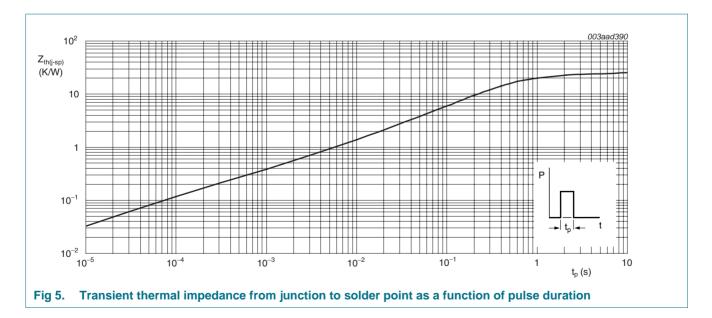
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5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j\text{-sp})}$	thermal resistance from junction to solder point	see Figure 5	-	-	25	K/W
R _{th(j-a)}	thermal resistance from		-	150	-	K/W
	junction to ambient		-	60	-	K/W



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6. Characteristics

Table 6. Characteristics

Table 0.	Onaracteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I _{GT}	gate trigger current	$V_D = 12 \text{ V; } T_j = 25 \text{ °C; } T2+ \text{ G-;}$ see Figure 6	-	-	3	mA
		V _D = 12 V; T _j = 25 °C; T2- G-	-	-	3	mΑ
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C}; T2+ G+$	-	-	3	mA
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C}; T2- G+$	-	-	5	mA
lL	latching current	$V_D = 12 \text{ V; } T_j = 25 \text{ °C; } I_G = 0.1 \text{ A; } T2 + G-;$ see Figure 7	-	-	15	mA
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C}; I_G = 0.1 \text{ A}; T2+ G+$	-	-	7	mΑ
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C}; I_G = 0.1 \text{ A}; T2- G+$	-	-	7	mΑ
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C}; I_G = 0.1 \text{ A}; T2- G-$	-	-	7	mA
I _H	holding current	$V_D = 12 \text{ V; } T_j = 25 \text{ °C; see } \frac{\text{Figure 10}}{\text{ occ}}$	-	-	7	mA
V_{T}	on-state voltage	I _T = 1 A; see <u>Figure 8</u>	-	1.3	1.6	V
V_{GT}	gate trigger voltage	$I_T = 0.1 \text{ A}; V_D = 12 \text{ V}; T_j = 25 \text{ °C};$ see <u>Figure 9</u>	-	-	1.3	V
		$I_T = 0.1 \text{ A}; V_D = 600 \text{ V}; T_j = 125 ^{\circ}\text{C}$	0.2	-	-	V
D	off-state current	V _D = 600 V; T _j = 125 °C	-	-	0.5	mA
Dynamic (characteristics					
dV _D /dt	rate of rise of off-state voltage	V _{DM} = 402 V; T _j = 110 °C; gate open circuit; see <u>Figure 11</u>	10	-	-	V/µs
dV _{com} /dt	rate of rise of commutating voltage	$V_D = 400 \text{ V}; T_j = 110 \text{ °C};$ $dI_{com}/dt = 0.44 \text{ A/ms}; \text{ gate open circuit}$	0.5	-	-	V/µs

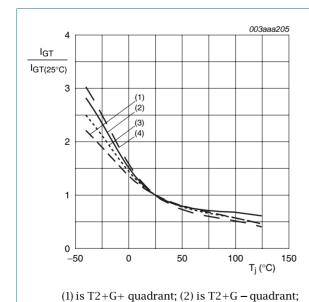


Fig 6. Normalized gate trigger current as a function of junction temperature

(3) is T2 - G – quadrant; (4) is T2 - G+ quadrant

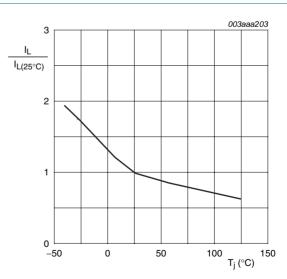
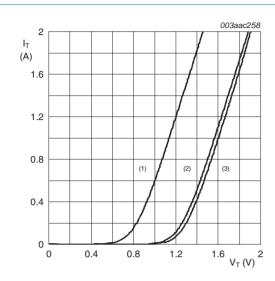


Fig 7. Normalized latching current as a function of junction temperature

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$$V_0 = 1.254 \text{ V; R}_s = 0.31 \Omega$$
 (1) $T_j = 125 \,^{\circ}\text{C; typical values}$

(2) $T_j = 125$ °C; maximum values (3) $T_j = 25$ °C; maximum values

Fig 8. On-state current as a function of on-state voltage

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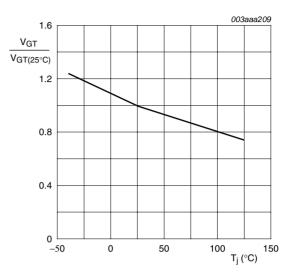


Fig 9. Normalized gate trigger voltage as a function of junction temperature

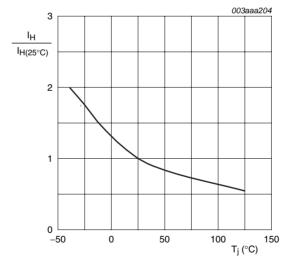


Fig 10. Normalized holding current as a function of junction temperature

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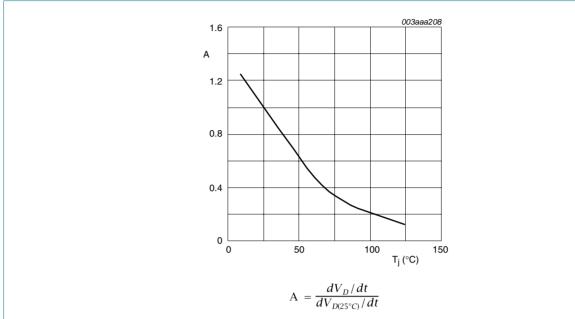


Fig 11. Normalized critical rate of rise of off-state voltage as a function of junction temperature;typical values

7. Package outline

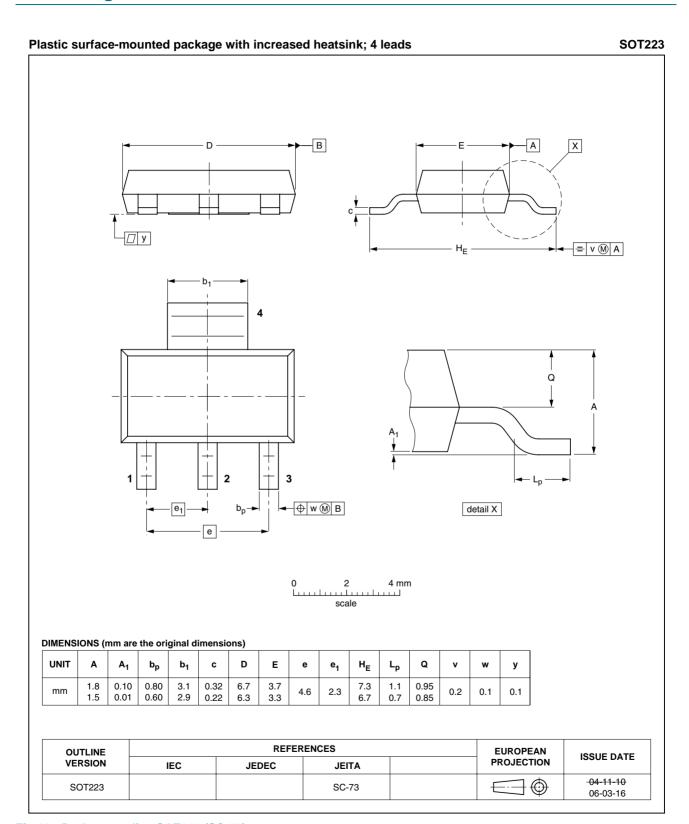


Fig 12. Package outline SOT223 (SC-73)

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Revision history

Table 7. **Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
Z0103MN_3	20090805	Product data sheet	-	Z0103_07_09_SERIES-02
Modifications:		of this data sheet has beer of NXP Semiconductors.	n redesigned to cor	nply with the new identity
	 Legal texts 	have been adapted to the	new company nam	e where appropriate.
	 Type number 	er Z0103MN separated from	m data sheet Z010	3_07_09_SERIES-02.
Z0103_07_09_SERIES-02 (9397 750 10102)	20020912	Product data	-	Z0103_07_09_SERIES-01
Z0103_07_09_SERIES-01 (9397 750 09419)	20020411	Product data	-	-

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9.1 Data sheet status

Document status [1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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